



## SA9103C

# SINGLE PHASE BIDIRECTIONAL POWER/ENERGY METERING IC WITH SERIAL INTERFACE

### FEATURES

- Performs bidirectional active and reactive power/energy, frequency and voltage measurement
- Meets the IEC 521/1036 Specification requirements for Class 1 AC Watt hour meters
- Protected against ESD
- Total power consumption rating below 25mW
- Adaptable to different current sensor technologies
- Operates over a wide temperature range
- Serial interface having a RS232 protocol
- Precision voltage reference on-chip
- Tri-state output to allow parallel connection of devices

### DESCRIPTION

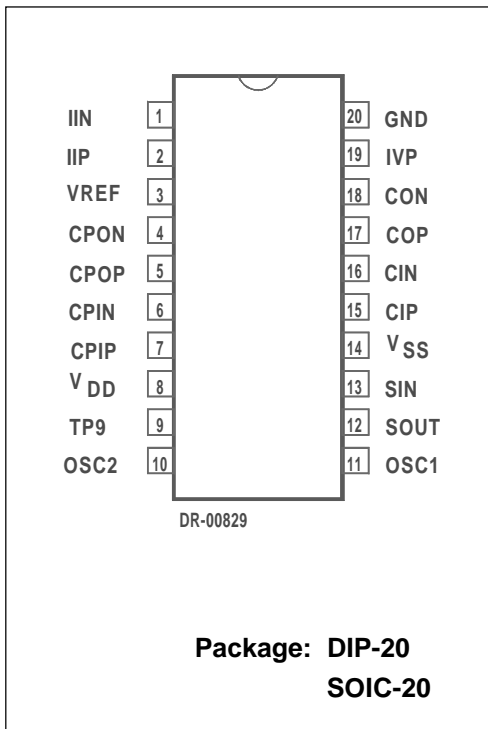
The SAMES SA9103C bidirectional Single Phase Power/Energy metering integrated circuit has a serial interface with a RS232 protocol, ideal for use with a  $\mu$ -Controller. The SA9103C performs the calculation for active and reactive power.

The integrated values for active and reactive energy as well as the mains frequency and voltage information are accessible through the RS232-Interface as 16 bit values.

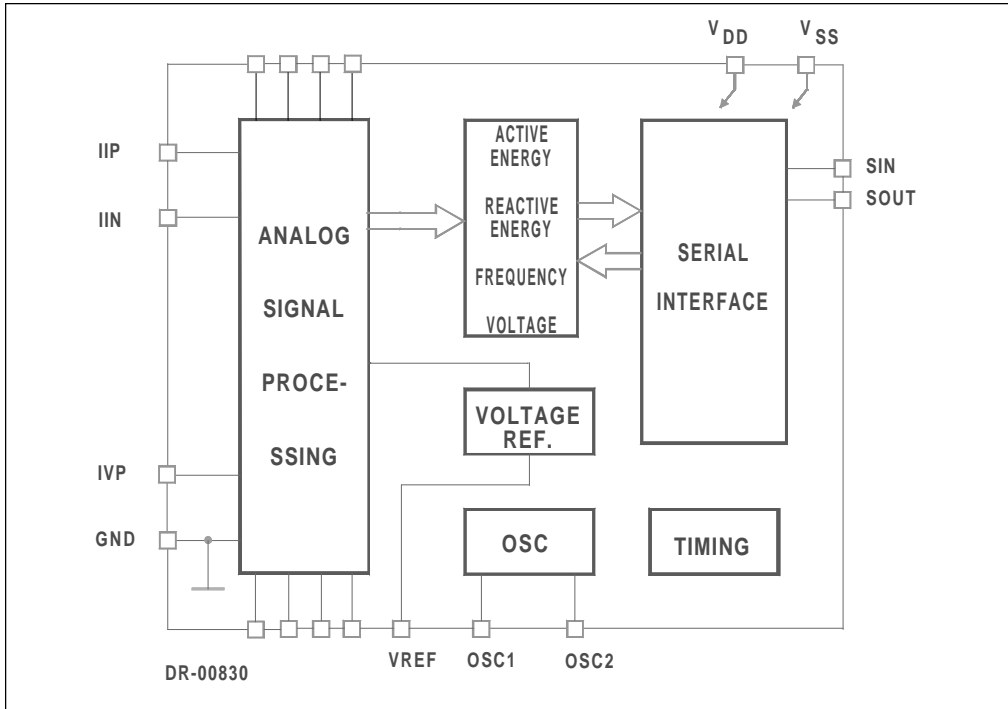
This innovative universal single phase power/energy metering integrated circuit is ideally suited for energy calculations in applications such as electricity dispensing systems (ED's), residential municipal metering and factory energy metering and control.

The SA9103C integrated circuit is available in both 20 pin dual-in-line plastic (DIP-20), as well as 20 pin small outline (SOIC-20) package types.

### PIN CONNECTIONS



**BLOCK DIAGRAM**



**ABSOLUTE MAXIMUM RATINGS\***

Parameter	Symbol	Min	Max	Unit
Supply Voltage	$V_{DD} - V_{SS}$	-0.3	6.0	V
Current on any pin	$I_{PIN}$	-150	+150	mA
Storage Temperature	$T_{STG}$	-40	+125	°C
Operating Temperature	$T_O$	-10	+70	°C

\* Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only. Functional operation of the device at these or any other condition above those indicated in the operational sections of this specification, is not implied. Exposure to Absolute Maximum Ratings for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS**

( $V_{DD} = 2.5V$ ,  $V_{SS} = -2.5V$ , over the temperature range  $-10^{\circ}C$  to  $+70^{\circ}C^{\#}$ , unless otherwise specified.)

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Supply Voltage: Positive	$V_{DD}$	2.25		2.75	V	
Supply Voltage: Negative	$V_{SS}$	-2.75		-2.25	V	
Supply Current: Positive	$I_{DD}$		5	6	mA	
Supply Current: Negative	$I_{SS}$		5	6	mA	
Current Sensor Inputs (Differential)						
Input Current Range	$I_{II}$	-25		+25	$\mu A$	Peak value
Voltage Sensor Input (Asymmetrical)						
Input Current Range	$I_{IV}$	-25		+25	$\mu A$	Peak value
Pin SOUT Output Low Voltage Output High Voltage	$V_{OL}$ $V_{OH}$	$V_{DD}-1$		$V_{SS}+1$	V V	$I_{OL} = 5mA$ $I_{OH} = -2mA$
Pin SIN Input High Voltage Input Low Voltage Pull-up Current	$V_{IH}$ $V_{IL}$ $-I_I$	$V_{DD}-1$ 50		$V_{SS}+1$ 150	V V $\mu A$	$V_{IN} = V_{SS}$
Oscillator	Recommended crystal: TV colour burst crystal $f = 3.5795$ MHz					
Pin VREF Ref. Current Ref. Voltage	$-I_R$ $V_R$	45 1.1	50	55 1.3	$\mu A$ V	With $R = 24k\Omega$ connected to $V_{SS}$ Referred to $V_{SS}$

<sup>#</sup> Extended Operating Temperature Range available on request.

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### PIN DESCRIPTION

Pin	Designation	Description
20	GND	Ground
8	V <sub>DD</sub>	Positive Supply Voltage
14	V <sub>SS</sub>	Negative Supply Voltage
19	IVP	Analog input for Voltage
1	IIN	Inputs for current sensor
2	IIP	
11	OSC1	Connections for crystal or ceramic resonator (OSC1 = Input ; OSC2 = Output)
10	OSC2	
12	SOUT	Serial Interface Out
13	SIN	Serial Interface In
4	CPON	Connections for outer loop capacitors of A/D converter (Voltage)
5	CPOP	
6	CPIN	Connections for inner loop capacitors of A/D converter (Voltage)
7	CPIP	
15	CIP	Connections for inner loop capacitors of A/D converter (Current)
16	CIN	
17	COP	Connections for outer loop capacitors of A/D converter (Current)
18	CON	
3	VREF	Connection for current setting resistor
9	TP9	Test Pin. Must be connected to V <sub>SS</sub>

### FUNCTIONAL DESCRIPTION

The SA9103C is a CMOS mixed signal Analog/Digital integrated circuit, which performs power/energy calculations across a power range of 1000:1, to an overall accuracy of better than Class 1.

The integrated circuit includes all the required functions for 1-phase power and energy measurement, such as two oversampling A/D converters for the voltage and current sense inputs, power calculation and energy integration. Internal offsets are eliminated through the use of cancellation procedures. The SA9103C integrates the measured active and reactive power consumption into 22 bit integrators, which are accessible via a serial port having a RS232 protocol. Two additional on-chip registers exist: one register contains the mains frequency information; and the other the voltage information.

## 1. Power calculation

In the Application Circuit (Figure 1), the voltage drop across the shunt will be between 0 and 16mV (0 to 80A through a shunt resistor of  $200\mu\Omega$ ). This voltage is converted to a current of between 0 and 16 $\mu$ A, by means of resistors  $R_1$  and  $R_2$ .

The current sense input saturates at an input current of  $\pm 25\mu$ A peak.

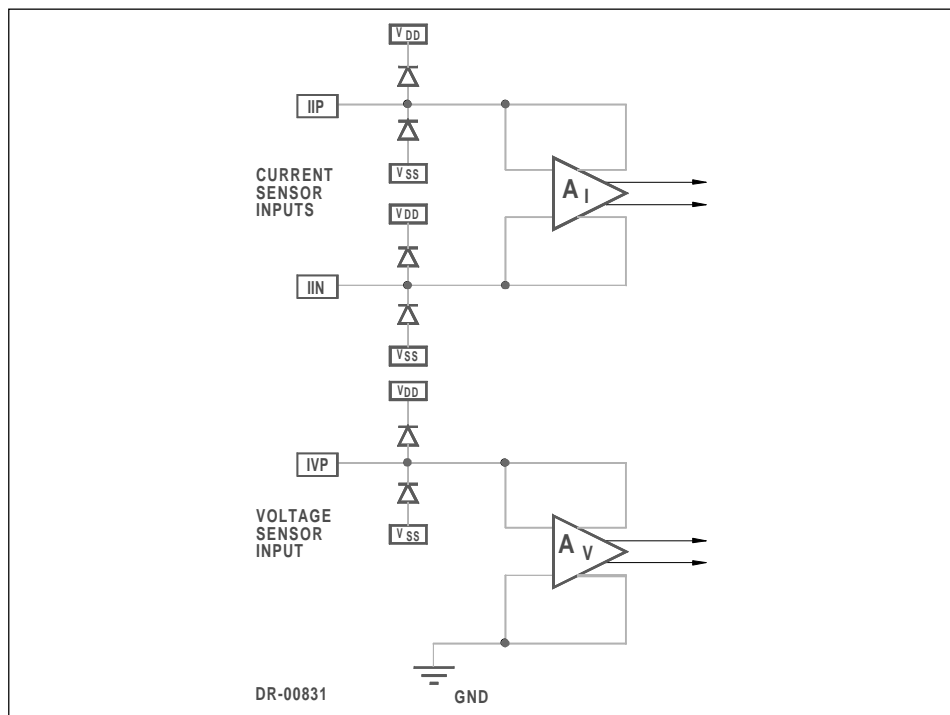
For the voltage sensor input, the mains voltage (230V AC) is divided down through a divider to 14V. The resulting current into the A/D converter input is 14 $\mu$ A at nominal voltage, via resistor R4 (1M $\Omega$ ).

In this configuration, with a mains voltage of 230V and a current of 80A, the SA9103C functions at its optimum conditions, having a margin of 3dB for overload available.

## 2. Analog Input Configuration

The input circuitry of the current and voltage sensor inputs are illustrated below. These inputs are protected against electrostatic discharge through clamping diodes.

The feedback loops from the outputs of the amplifiers  $A_I$  and  $A_V$  generate virtual shorts on the signal inputs. Exact duplications of the input currents are generated for the analog signal processing circuitry.



## SA9103C

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### 3. Electrostatic Discharge (ESD) Protection

The SA9103C integrated circuit's inputs/outputs are protected against ESD .

### 4. Power Consumption

The power consumption rating of the SA9103C integrated circuit is less than 25mW.

### 5. Serial Interface

Reading and resetting of the SA9103C's on-chip integrators, is performed via the serial interface.

The settings are:

- 19 200 Baud
- 1 Start bit (S)
- 1 Stop bit (E)
- No parity bits

The serial interface, with RS232 protocol, has been designed to operate directly with a PC (Personal Computer).

The serial interface allows for the following operations:

**Read Integrator (RD):** The SA9103C integrated circuit transmits the integrator status to the controller, after the current measurement cycle has been completed (8 mains periods maximum).

The register containing the mains frequency information is read only.

**Reset Integrator (RES):** The SA9103C integrator is reset, without transmitting the integrator status.

**Read/Reset Integrator (RD/RES):** The SA9103C transmits the integrator status and resets the integrator after the current measurement cycle has been completed.

In a typical application, the system controller monitors the status of the SA9103C's integrator using the "Read" command. At rated load conditions, the capacity of the 22 bit integrator allows for an integration time of 2 seconds prior to integrator overflow.

If after a "Read" command, the integrator value is sufficiently high, a "Read/Reset" command from the controller causes the SA9103C integrated circuit to complete the existing measurement cycle, transmit the 16 most significant bits of the 22 bit integrator via the Serial Output (SOUT) to the controller and restart the integrator.

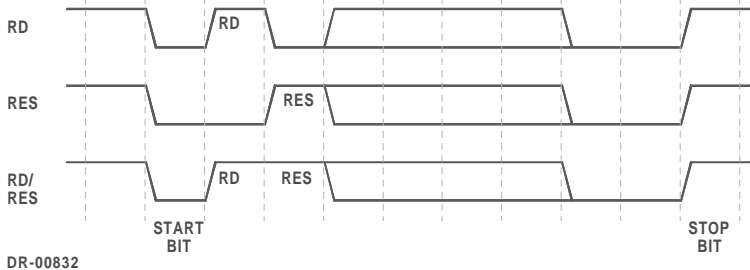
In order to ensure correct measurements, the integrator commands ("Read" and "Read/Reset") are only executed after completion of the internal offset calibration cycle. The cycle length is 8 mains periods.

Thus, for power calculations, the time value should be taken from the difference in time from the previously received energy value to the currently received value.

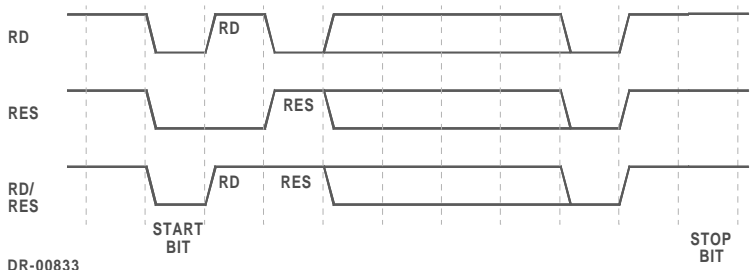


By adapting the "Read/Reset" rate to the line current the accuracy of the measurement can be achieved down to lowest signal levels.

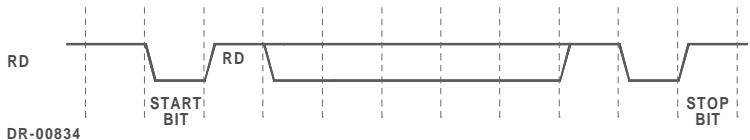
**Read, Reset and Read/Reset of integrator for active energy**



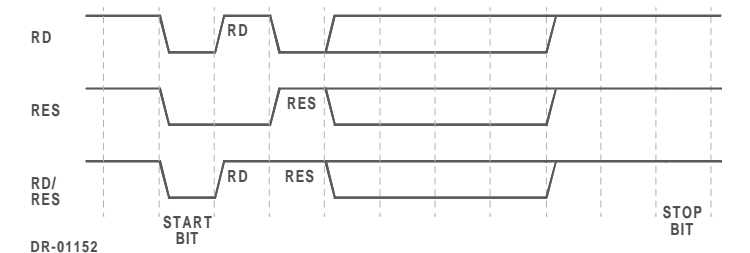
**Read, Reset and Read/Reset of integrator for reactive energy**



**Read frequency register**



**Read, Reset and Read/Reset of integrator for voltage**

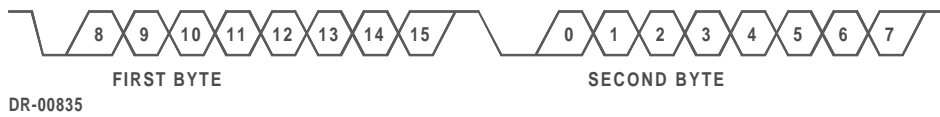


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The register access codes which can be written to the SA9103C via the serial communications port are shown in the table below.

REGISTER	READ	RESET	READ-RESET
ACTIVE	\$01	\$02	\$03
RE-ACTIVE	\$81	\$82	\$83
VOLTAGE	\$C1	\$C2	\$C3
FREQUENCY	\$41	-	-

### Data on SOUT



From the two bytes of data output by the device, the value for the register can be derived as shown:

$$\text{Register value} = (\text{First Byte} * 256) + \text{Second Byte}$$

The most significant bit of the 16 bit energy register (active or reactive) is an indication of the direction of the energy flow (0 = positive, 1 = negative).

## 6. Register Values

- a. The active and reactive energy measured per count, may be calculated by applying the following formula:

$$\text{Energy per Count} = \frac{V * I}{K} \text{ Watt seconds}$$

Where

V	=	Rated Voltage
I	=	Rated Current
K	=	9281 for Active Energy

$$\frac{9281 * 2}{\pi} \text{ for Reactive Energy}$$

- b. The mains frequency may be calculated as follows:

$$\text{Frequency} = \frac{\text{Crystal frequency}}{\text{Register Value} * 8}$$

- c. To calculate the measured voltage, the following formula may be used:

$$V_{\text{measured}} = \frac{V * n}{14000 * t}$$

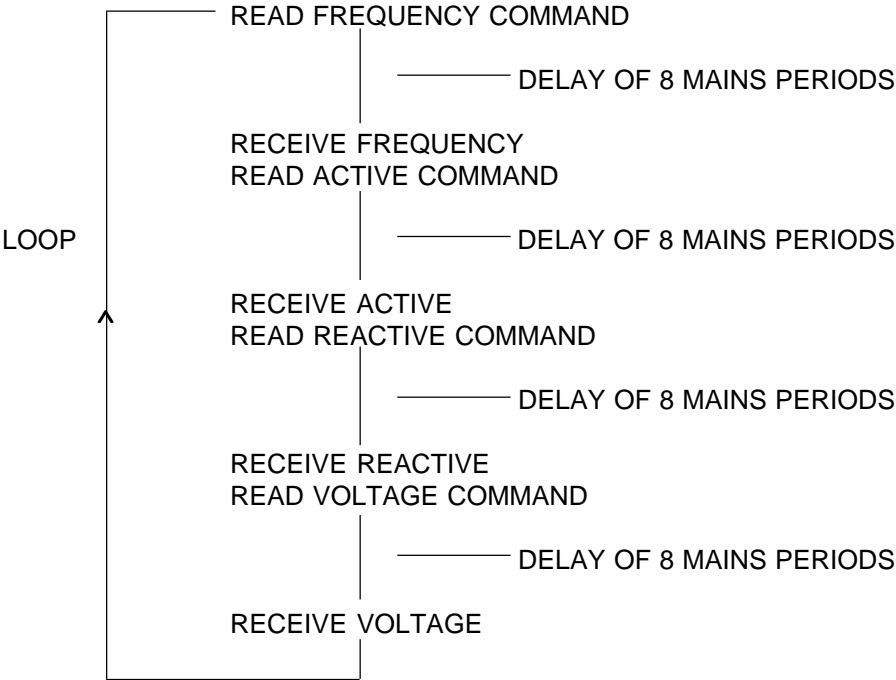
Where

V	=	rated voltage
t	=	time difference between successive reads
n	=	difference in register values between successive reads



7. Software flow

In an application in which all the registers must be accessed, the software loop illustrated below can be implemented.



The SA9103C integrated circuit transmits the register values only after completion of the current measurement cycle (8 mains periods maximum).

The delay of 8 mains periods can be calculated from the period value of the frequency returned by the initial read, and updated with each subsequent reading of frequency.

Each successive read of the registers takes place regularly at intervals of 4 blocks of 8 mains cycles. This time and the difference between successive energy register values can be used to calculate power.

### 8. Calibration

For the calibration of the SA9103C, the following procedure is recommended:

- a. Establish calibration factor for active energy (Ka) at pf close to 1.

$$\text{Active (Measured)} = \text{register\_value (Active)} * \text{Ka.} \quad \textcircled{1}$$

- b. The factor for reactive (Kr) is typically Ka \* PI/2.  
For higher accuracy of Kr, establish Kr at pf close to 0.

$$\text{Reactive (Measured)} = \text{register\_value (Reactive)} * \text{Kr} \quad \textcircled{2}$$

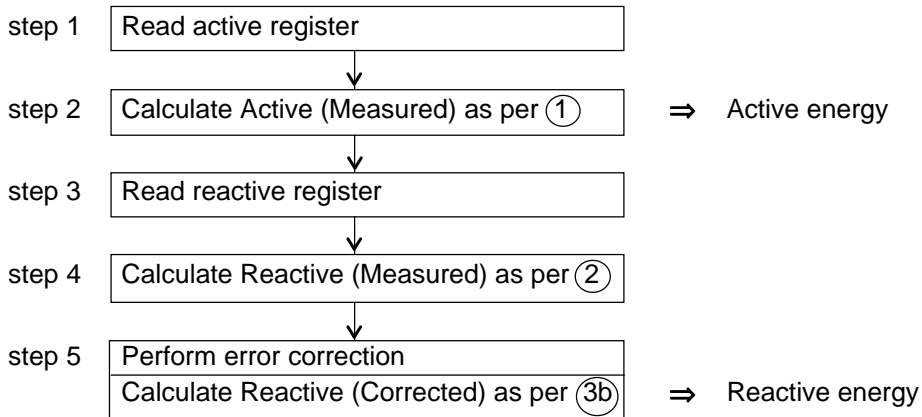
- c. At pf close to 1, establish error for reactive (Er)

$$\text{Er} = (\text{Reactive (Measured)} - \text{Reactive (True)}) / \text{Active (Measured)} \quad \textcircled{3}$$

$$\text{Reactive (Corrected)} = \text{Reactive (Measured)} - \text{Er} * \text{Active (Measured)} \quad \textcircled{3b}$$

### Measurement

Having determined the scaling factors (Ka & Kr) and error correction constant (Er) the measurement cycle consists of the following steps:



The above five steps must be performed for each measurement cycle.



## TYPICAL APPLICATIONS

In the Application Circuits (Figures 1 and 2), the components required for power metering applications, are shown.

In Figure 1 a shunt resistor is used for current sensing. In this application, the circuitry requires a +2.5V, 0V, -2.5V DC supply.

In the case of Figure 2, when using a current transformer for current sensing, a +5V, 0V DC supply is sufficient for the circuit.

The most important external components for the SA9103C integrated circuit are:

$C_1$  and  $C_2$  are the outer loop capacitors for the two integrated oversampling A/D converters. The value of these capacitors is 560pF. The actual values determine the signal to noise and stability performance. The tolerances should be within  $\pm 10\%$ .

$C_3$  and  $C_4$  are the inner loop capacitors of the A/D converters. The optimum value is 3.3nF. The actual values are uncritical. Values smaller than 0.5nF and larger than 5nF should be avoided.

$R_1$ ,  $R_2$  and RSH are the resistors defining the current level into the current sense input. The values should be selected for an input current of 16 $\mu$ A into the SA9103C at rated line current.

Values for RSH of less than 200 $\mu\Omega$  should be avoided.

$$R_1 = R_2 = (I_L / 16\mu A) * RSH / 2$$

Where  $I_L$  = Line current

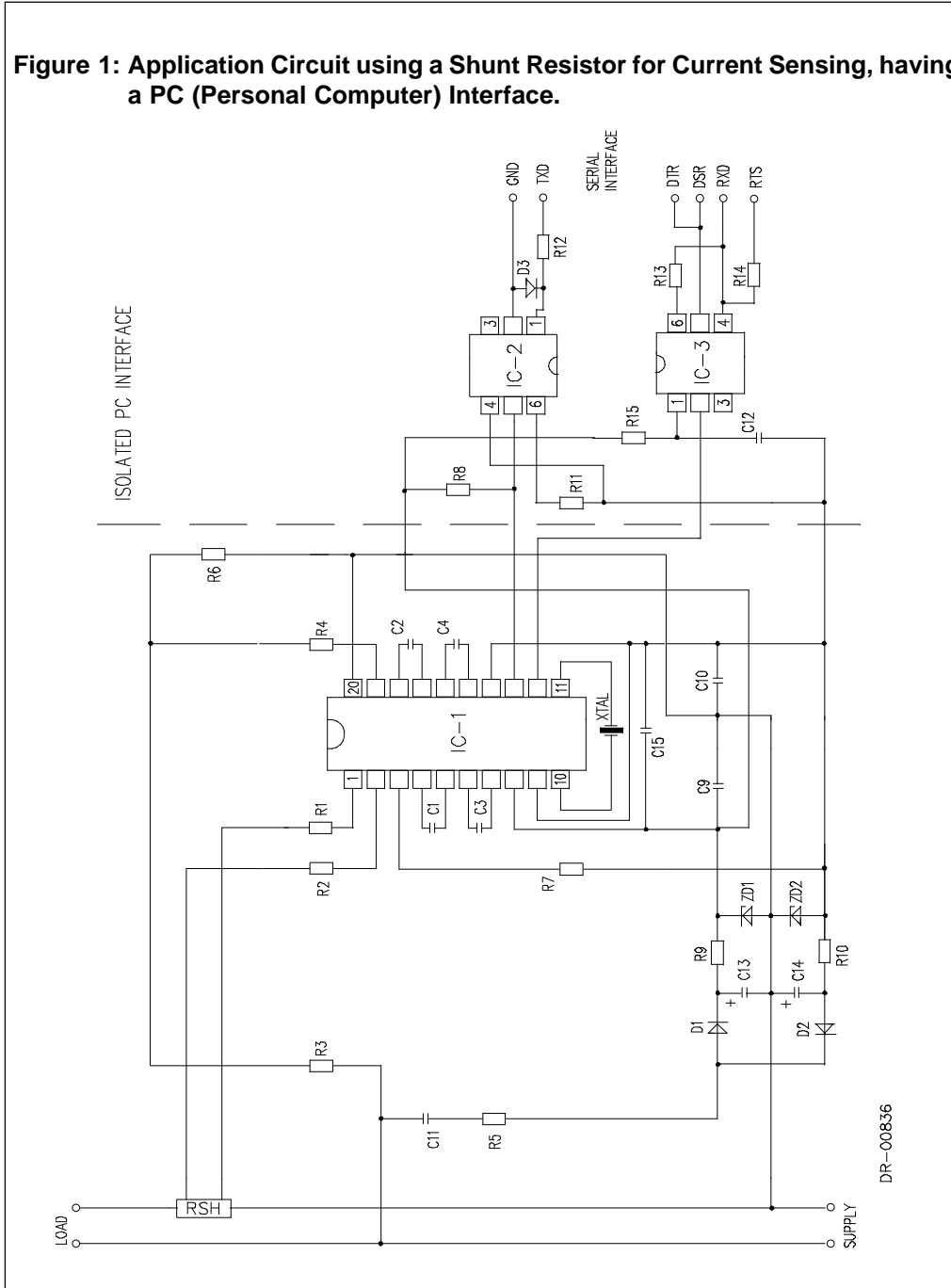
RSH = Shunt resistor/termination resistor

$R_3$ ,  $R_6$  and  $R_4$  set the current for the voltage sense input. The values should be selected so that the input current into the voltage sense input (virtual ground) is set to 14 $\mu$ A.

$R_7$  defines all on-chip bias and reference currents. With  $R_7 = 24k\Omega$ , optimum conditions are set.

XTAL is a colour burst TV crystal ( $f = 3.5795\text{MHz}$ ) for the oscillator. The oscillator frequency is divided down to 1.7897MHz on-chip to supply the A/D converters and digital circuitry.

**Figure 1: Application Circuit using a Shunt Resistor for Current Sensing, having a PC (Personal Computer) Interface.**



## Part List for Application Circuit: Figure 1

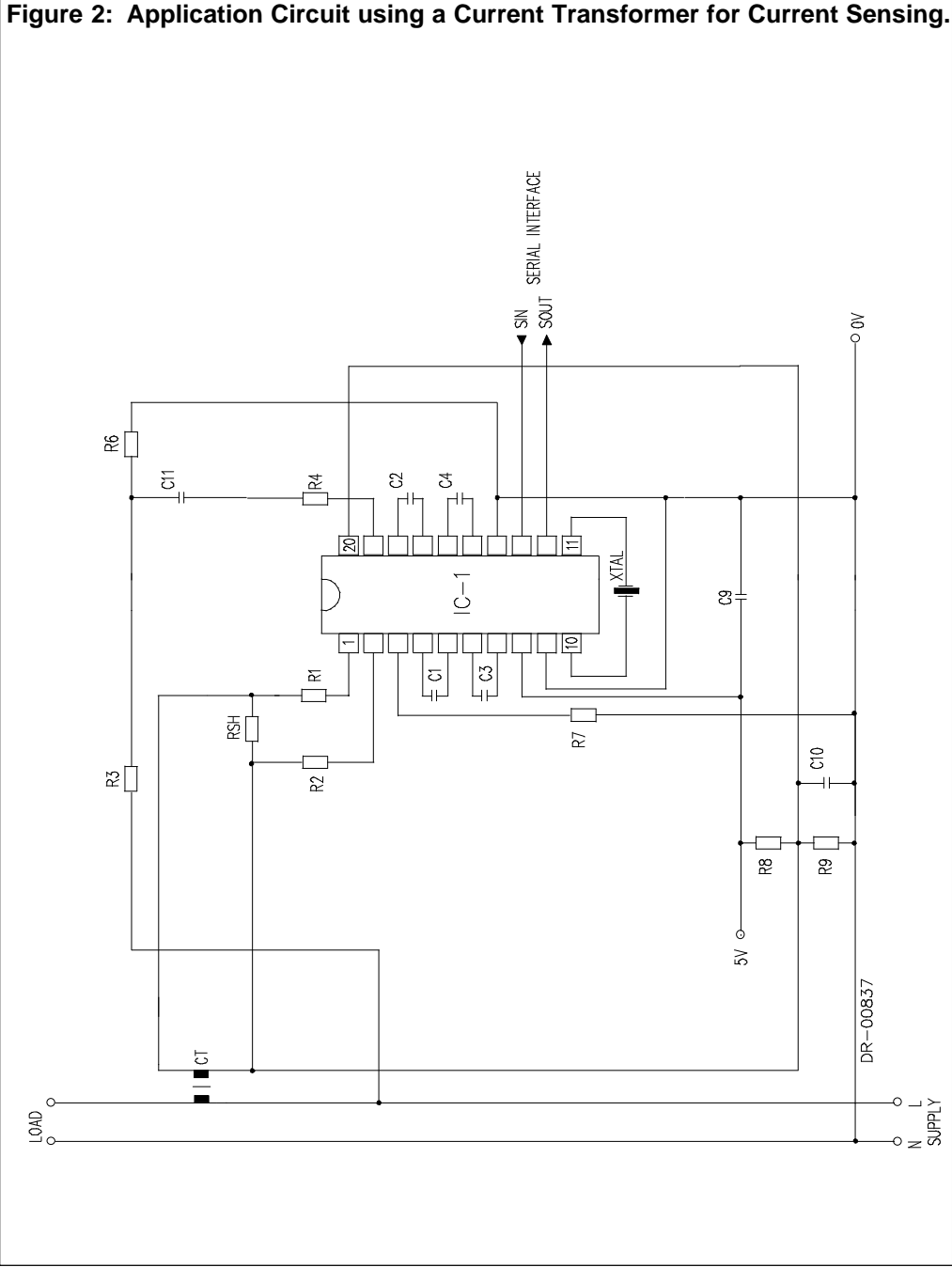
Item	Symbol	Description	Detail
1	IC-1	SA9103C	DIP-20/SOIC-20
2	IC-2	Opto Coupler 4N35	DIP-6
3	IC-3	Opto Coupler 4N35	DIP-6
4	D1	Diode, Silicon, 1N4148	
5	D2	Diode, Silicon, 1N4148	
6	D3	Diode, Silicon, 1N4148	
7	ZD1	Diode, Zener, 2.4V, 200mW	
8	ZD2	Diode, Zener, 2.4V, 200mW	
9	XTAL	Crystal, 3.5795MHz	Colour burst TV
10	R1	Resistor, 1% metal	Note 1
11	R2	Resistor, 1% metal	Note 1
12	R3	Resistor, 390k, (230VAC), 1% metal	
13	R4	Resistor, 1M, 1/4W, 1% metal	
14	R5	Resistor, 470 $\Omega$ , 2W, 5%, carbon	
15	R6	Resistor, 24k, 1/4W, 1%, metal	
16	R7	Resistor, 24k, 1/4W, 1%, metal	
17	R8	Resistor, 680 $\Omega$ , 1/4W, 5%	
18	R9	Resistor, 680 $\Omega$ , 1/4W, 5%	
19	R10	Resistor, 680 $\Omega$ , 1/4W, 5%	
20	R11	Resistor, 100k, 1/4W, 5%	
21	R12	Resistor, 120 $\Omega$ , 1/4W, 5%	
22	R13	Resistor, 120k, 1/4W, 5%	
23	R14	Resistor, 3.9k, 1/4W, 5%	
24	R15	Resistor, 120 $\Omega$ , 1/4W, 5%	
25	C1	Capacitor, 560pF	
26	C2	Capacitor, 560pF	
27	C3	Capacitor, 3.3nF	
28	C4	Capacitor, 3.3nF	
29	C9	Capacitor, 100nF	
30	C10	Capacitor, 100nF	
31	C11	Capacitor, 0.47 $\mu$ F, 250VAC, polyester	
32	C12	Capacitor, 100nF	
33	C13	Capacitor, 100 $\mu$ F	
34	C14	Capacitor, 100 $\mu$ F	
35	C15	Capacitor, 820nF	
36	RSH	Shunt Resistor	Note 2

Note 1: Resistor (R1 and R2) values are dependant upon the selected value of RSH.

Note 2: See TYPICAL APPLICATIONS when selecting the value for RSH.



Figure 2: Application Circuit using a Current Transformer for Current Sensing.



**Parts List for Application Circuit: Figure 2**

Item	Symbol	Description	Detail
1	IC-1	SA9103C	DIP-20/SOIC-20
2	XTAL	Crystal, 3.5795MHz	Colour burst TV
3	RSH	Resistor	Note 1
4	R1	Resistor, 1%, metal	Note 2
5	R2	Resistor, 1%, metal	Note 2
6	R3	Resistor, 390k, (230VAC) 1%, metal	
7	R4	Resistor, 1M, 1/4W, metal	
8	R6	Resistor, 24k, 1/4W, metal	
9	R7	Resistor, 24k, 1/4W, metal	
10	R8	Resistor, 2.2k, 1/4W, 5%	
11	R9	Resistor, 2.2k, 1/4W, 5%	
12	C1	Capacitor, 560pF	
13	C2	Capacitor, 560pF	
14	C3	Capacitor, 3.3nF	
15	C4	Capacitor, 3.3nF,	
16	C9	Capacitor, 820nF	Note 3
17	C10	Capacitor, 100nF	
18	C11	Capacitor	Note 4
19	CT	Current Transformer	

Note 1: See TYPICAL APPLICATIONS when selecting the value of RSH.

Note 2: Resistor (R1 and R2) values are dependant upon the selected value of RSH.

Note 3: Capacitor (C9) to be positioned as close to IC-1, as possible.

Note 4: Capacitor (C11) selected for DC blocking and to minimize phase error introduced by the current transformer.

Part Number	Package
SA9103CPA	DIP-20
SA9103CSA	SOIC-20

## SA9103C

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